OPB706A, OPB706B, OPB706C OPB707A, OPB707B, OPB707C

Features:

- Choice of Phototransistor (OPB706) or Photodarlington (OPB707) output
- Unfocused for sensing diffuse surface
- Low cost plastic housing
- Designed for use with PCBoards or connectors

Description:



The **OPB706** consists of an infrared Light Emitting Diode (LED) and an NPN silicon Phototransistor mounted "side-by-side" on parallel axes in a black plastic housing. The **OPB707** consists of an infrared LED and an NPN silicon Photodarlington mounted "side-by-side" on parallel axes in a black plastic housing.

On both **OPB706** and **OPB707**, the LED and Phototransistor / Photodarlington are molded using dark infrared transmissive plastic to reduce ambient light noise. The Phototransistor / Photodarlington responds to light from the emitter when a reflective object passes within its field of view of the device.

Custom electrical, wire and cabling and connectors are available. Contact your local representative or OPTEK for more information.

Applications:

- Non-contact reflective object sensor
- Assembly line automation
- Machine automation
- Machine safety
- End of travel sensor
- Door sensor





General Note

TT Electronics reserves the right to make changes in product specification without notice or liability. All information is subject to TT Electronics' own data and is considered accurate at time of going to print. OPTEK Technology, Inc. 1645 Wallace Drive, Carrollton, TX 75006IPh: +1 972 323 2200 www.optekinc.com I www.ttelectronics.com

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Absolute Maximum Ratings (T _A ≈ 25° C unless otherwise noted)		
Storage and Operating Temperature Range	-40° C to +85° C	
Lead Soldering Temperature [1/16 inch (1.6mm) from the case for 5 sec. with soldering iron] ⁽¹⁾	260° (
nput Diode		
Forward DC Current	50 mA	
Peak Forward Current (1 µs pulse width, 300 pps)	3 A	
Reverse DC Voltage	2 \	
Power Dissipation ⁽²⁾	75 mW	
Output Phototransistor (OPB706) Output Photodarlington (OPB707)		
Collector-Emitter Voltage		
OPB706	24 \	
OPB707	15 \	
Emitter-Collector Voltage	5 \	
Collector DC Current		
OPB706	25 m/	
OPB707	125 m/	
Power Dissipation		
OPB706 ⁽²⁾	75 mV	
OPB707 ⁽³⁾	100 mV	

Notes:

(1) RMA flux is recommended. Duration can be extended to 10 seconds maximum when flow soldering.

(2) Derate linearly 1.25 mW/°C above 25 ° C.

(3) Derate linearly 1.67 mW/°C above 25 ° C.

OPB706A, OPB706B, OPB706C OPB707A, OPB707B, OPB707C



Electrical Characteristics (T _A = 25° C unless otherwise noted)							
SYMBOL	PARAMETER	MIN	ТҮР	MAX	UNITS	TEST CONDITIONS	
Input Diode (see OP165W for additional information)							
V _F	Forward Voltage	-	-	1.7	V	I _F = 20 mA	
I _R	Reverse Current	-	-	100	μΑ	V _R = 2 V	
Output Phototransistor (see OP505W for additional information) Photodarlington (see OP535 for additional information)							
V _{(BR)CEO}	Collector-Emitter Brealdown Voltage OPB706 OPB707	24 15	-		V	I _C = 100 μA	
V _{(BR)ECO}	Emitter-Collector Breakdown Voltage	5	-	-	V	I _E = 100 μA	
I _{CEO}	Collector Dark Current OPB706 OPB707	-	-	100 250	nA	$V_{CE} = 5 \text{ V}, \text{ I}_{F} = 0, \text{ E}_{E} \le 0.1 \mu\text{W/cm}^{2}$	
Combine	d	-					
I _{CX}	Crosstalk OPB706 OPB707	-	-	200 10	nA μA	$I_F = 20 \text{ mA}, V_{CE} = 5 \text{ V}, \text{ No reflecting surface}^{(1)}$	
I _{C(ON)}	On-State Collector Current OPB706A OPB706B OPB706C	500 350 250	- - -		μΑ	I _F = 20 mA, V _{CE} = 5V , d = 0.05" (1.27 mm) ^{(2) (3)}	
	OPB707A OPB707B OPB707C	25 17 10	- - -		mA		
V _{CE} (_{SAT)}	Collector-Emitter Saturation Voltage OPB706 OPB707	0.4 1.1	-	-	V	$I_{F} = 20 \text{ mA, } d = 0.05'' (1.27 \text{ mm})^{(2) (3)}$ $I_{C(ON)} = 100 \mu \text{A}$ $I_{C(ON)} = 2 \text{ mA}$	

Notes:

(1) Crosstalk (I_{CX}) is the collector current measured with the indicated current in the input diode and with no reflecting surface.

(2) The distance from the assembly face to the reflective surface is "d".

(3) Measured using Eastman Kodak neutral white test card with 90% diffuse reflectance as a reflecting surface. Reference: Eastman Kodak, Catalog #E 152 7795.

(4) Lower curve is a calculated worst case condition rather than the conventional -2 Ω limit.

(5) All parameters tested using pulse techniques.

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OPB706 - Normalized Collector Current vs. Object Distance

OPB707 - Normalized Collector Current vs. Object Distance



OPB706 - Output Current vs Forward Current vs Temperature



OPB707 - Output Current vs Forward Current vs Temperature



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